E·XFL



Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Obsolete
PowerPC e500
1 Core, 32-Bit
1.2GHz
Signal Processing; SPE, Security; SEC
DDR, DDR2, SDRAM
No
-
10/100/1000Mbps (4)
-
-
1.8V, 2.5V, 3.3V
0°C ~ 105°C (TA)
Cryptography, Random Number Generator
783-BBGA, FCBGA
783-FCBGA (29x29)
https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8548evuatg

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

4.5 Platform to FIFO Restrictions

Note the following FIFO maximum speed restrictions based on platform speed.

For FIFO GMII mode:

FIFO TX/RX clock frequency ≤ platform clock frequency/4.2

For example, if the platform frequency is 533 MHz, the FIFO TX/RX clock frequency must be no more than 127 MHz.

For FIFO encoded mode:

FIFO TX/RX clock frequency \leq platform clock frequency/4.2

For example, if the platform frequency is 533 MHz, the FIFO TX/RX clock frequency must be no more than 167 MHz.

4.6 Platform Frequency Requirements for PCI-Express and Serial RapidIO

The CCB clock frequency must be considered for proper operation of the high-speed PCI-Express and Serial RapidIO interfaces as described below.

For proper PCI Express operation, the CCB clock frequency must be greater than:

See *MPC8548ERM*, *Rev.* 2, *PowerQUICC III Integrated Processor Family Reference Manual*, Section 18.1.3.2, "Link Width," for PCI Express interface width details.

For proper serial RapidIO operation, the CCB clock frequency must be greater than:

 $2 \times (0.80) \times (Serial RapidIO interface frequency) \times (Serial RapidIO link width)$

64

See *MPC8548ERM*, *Rev.* 2, *PowerQUICC III Integrated Processor Family Reference Manual*, Section 17.4, "1x/4x LP-Serial Signal Descriptions," for serial RapidIO interface width and frequency details.

4.7 Other Input Clocks

For information on the input clocks of other functional blocks of the platform see the specific section of this document.

6.2.2 DDR SDRAM Output AC Timing Specifications

Table 19. DDR SDRAM Output AC Timing Specifications

At recommended operating conditions.

Parameter	Symbol ¹	Min	Мах	Unit	Notes
MCK[n] cycle time, MCK[<i>n</i>]/MCK[<i>n</i>] crossing	t _{MCK}	3.75	6	ns	2
ADDR/CMD output setup with respect to MCK 533 MHz 400 MHz 333 MHz	t _{DDKHAS}	1.48 1.95 2.40		ns	3
ADDR/CMD output hold with respect to MCK 533 MHz 400 MHz 333 MHz	^t ddkhax	1.48 1.95 2.40		ns	3
MCS[<i>n</i>] output setup with respect to MCK 533 MHz 400 MHz 333 MHz	^t DDKHCS	1.48 1.95 2.40		ns	3
MCS[<i>n</i>] output hold with respect to MCK 533 MHz 400 MHz 333 MHz	^t DDKHCX	1.48 1.95 2.40		ns	3
MCK to MDQS Skew	t _{DDKHMH}	-0.6	0.6	ns	4
MDQ/MECC/MDM output setup with respect to MDQS 533 MHz 400 MHz 333 MHz	^t DDKHDS, ^t DDKLDS	538 700 900	 	ps	5
MDQ/MECC/MDM output hold with respect to MDQS 533 MHz 400 MHz 333 MHz	^t ddkhdx, ^t ddkldx	538 700 900		ps	5
MDQS preamble start	t _{DDKHMP}	$-0.5\times t_{MCK}-0.6$	$-0.5 imes t_{MCK}$ + 0.6	ns	6



Figure 7. FIFO Receive AC Timing Diagram

8.2.2 GMII AC Timing Specifications

This section describes the GMII transmit and receive AC timing specifications.

8.2.2.1 GMII Transmit AC Timing Specifications

This table provides the GMII transmit AC timing specifications.

Table 26.	GMII	Transmit	AC	Timing	Specifications
-----------	------	----------	----	--------	-----------------------

Parameter/Condition	Symbol ¹	Min	Тур	Max	Unit
GMII data TXD[7:0], TX_ER, TX_EN setup time	t _{GTKHDV}	2.5	_	_	ns
GTX_CLK to GMII data TXD[7:0], TX_ER, TX_EN delay	t _{GTKHDX}	0.5	_	5.0	ns
GTX_CLK data clock rise time (20%–80%)	t _{GTXR} ²	_	_	1.0	ns
GTX_CLK data clock fall time (80%–20%)	t _{GTXF} 2	—		1.0	ns

Notes:

The symbols used for timing specifications follow the pattern t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t_{(first two letters of functional block)(reference)(state)(signal)(state)} for outputs. For example, t_{GTKHDV} symbolizes GMII transmit timing (GT) with respect to the t_{GTX} clock reference (K) going to the high state (H) relative to the time date input signals (D) reaching the valid state (V) to state or setup time. Also, t_{GTKHDX} symbolizes GMII transmit timing (GT) with respect to the high state (H) relative to the time date input signals (D) reaching the clock reference (K) going to the high state (H) relative to the time date input signals (D) going invalid (X) or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{GTX} represents the GMII(G) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub>

2. Guaranteed by design.

l²C

13 I²C

This section describes the DC and AC electrical characteristics for the I²C interfaces of the device.

13.1 I²C DC Electrical Characteristics

This table provides the DC electrical characteristics for the I^2C interfaces.

Table 45. I²C DC Electrical Characteristics

Parameter	Symbol	Min	Мах	Unit	Notes
Input high voltage level	V _{IH}	$0.7 \times OV_{DD}$	OV _{DD} + 0.3	V	_
Input low voltage level	V _{IL}	-0.3	$0.3\times\text{OV}_{\text{DD}}$	V	
Low level output voltage	V _{OL}	0	$0.2\times \text{OV}_{\text{DD}}$	V	1
Pulse width of spikes which must be suppressed by the input filter	t _{I2KHKL}	0	50	ns	2
Input current each I/O pin (input voltage is between $0.1 \times OV_{DD}$ and $0.9 \times OV_{DD}$ (max)	I	-10	10	μA	3
Capacitance for each I/O pin	CI		10	pF	_

Notes:

1. Output voltage (open drain or open collector) condition = 3 mA sink current.

- 2. See the MPC8548E PowerQUICC[™] III Integrated Processor Family Reference Manual, for information on the digital filter used.
- 3. I/O pins obstruct the SDA and SCL lines if $\ensuremath{\mathsf{OV}_{\mathsf{DD}}}$ is switched off.

13.2 I²C AC Electrical Specifications

This table provides the AC timing parameters for the I^2C interfaces.

Table 46. I²C AC Electrical Specifications

Parameter	Symbol ¹	Min	Мах	Unit	Notes
SCL clock frequency	f _{I2C}	0	400	kHz	—
Low period of the SCL clock	t _{I2CL}	1.3	—	μS	4
High period of the SCL clock	t _{I2CH}	0.6	—	μS	4
Setup time for a repeated START condition	t _{I2SVKH}	0.6	—	μS	4
Hold time (repeated) START condition (after this period, the first clock pulse is generated)	t _{I2SXKL}	0.6	—	μs	4
Data setup time	t _{I2DVKH}	100	—	ns	4
Data input hold time: CBUS compatible masters I ² C bus devices	t _{I2DXKL}	0		μS	2
Data output delay time:	t _{I2OVKL}	—	0.9	—	3
Set-up time for STOP condition	t _{I2PVKH}	0.6	—	μs	—
Bus free time between a STOP and START condition	t _{I2KHDX}	1.3	—	μS	

3.	The maximum t _{I2DXKL}	has only to be met if the device does not stretch the LOW period (t_{I2CL}) of the SCL signal	al.

For the detail of I²C frequency calculation, see Determining the I²C Frequency Divider Ratio for SCL (AN2919). Note that the

200 MHz

390 kHz

0x26

512

133 MHz

346 kHz

0x00

384

4. Guaranteed by design.

FDR bit setting

I²C source clock frequency

Actual FDR divider selected

Actual I²C SCL frequency generated

Figure 33 provides the AC test load for the I^2C .



Figure 33. I²C AC Test Load

57

Table 46. I²C AC Electrical Specifications (continued)

Parameter	Symbol ¹	Min	Мах	Unit	Notes
Noise margin at the LOW level for each connected device (including hysteresis)	V _{NL}	$0.1 \times OV_{DD}$	—	V	—
Noise margin at the HIGH level for each connected device (including hysteresis)	V _{NH}	$0.2 \times OV_{DD}$	—	V	_

Notes:

1. The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, t_{12DVKH} symbolizes I²C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{12C} clock reference (K) going to the high (H) state or setup time. Also, t_{12SXKL} symbolizes I²C timing (I2) for the time that the data with respect to the start condition (S) went invalid (X) relative to the t_{12C} clock reference (K) going to the stop condition (P) reaching the valid state (V) relative to the t_{12C} clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).}

2. As a transmitter, the device provides a delay time of at least 300 ns for the SDA signal (see the V_{IH}(min) of the SCL signal) to bridge the undefined region of the falling edge of SCL to avoid unintended generation of Start or Stop condition. When the device acts as the I²C bus master while transmitting, the device drives both SCL and SDA. As long as the load on SCL and SDA are balanced, the device would not cause unintended generation of Start or Stop condition. Therefore, the 300 ns SDA output delay time is not a concern. If, under some rare condition, the 300 ns SDA output delay time is required for the device as a transmitter, the following setting is recommended for the FDR bit field of the I2CFDR register to ensure both the desired I²C SCL clock frequency and SDA output delay time are achieved, assuming that the desired I²C SCL clock frequency is 400 kHz and the Digital Filter Sampling Rate Register (I2CDFSRR) is programmed with its default setting of 0x10 (decimal 16):

266 MHz

378 kHz

0x05

704

333 MHz

0x2A

371 kHz

896

I²C source clock frequency is half of the CCB clock frequency for the device.

PCI/PCI-X

Table 54. PCI-X AC Timing Specifications at 133 MHz (continued)

Parameter	Symbol	Min	Max	Unit	Notes
HRESET to PCI-X initialization pattern hold time	t _{PCRHIX}	0	50	ns	6, 12

Notes:

1. See the timing measurement conditions in the PCI-X 1.0a Specification.

- 2. Minimum times are measured at the package pin (not the test point). Maximum times are measured with the test point and load circuit.
- 3. Setup time for point-to-point signals applies to REQ and GNT only. All other signals are bused.
- 4. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 5. Setup time applies only when the device is not driving the pin. Devices cannot drive and receive signals at the same time.
- 6. Maximum value is also limited by delay to the first transaction (time for HRESET high to first configuration access, t_{PCRHFV}). The PCI-X initialization pattern control signals after the rising edge of HRESET must be negated no later than two clocks before the first FRAME and must be floated no later than one clock before FRAME is asserted.
- 7. A PCI-X device is permitted to have the minimum values shown for t_{PCKHOV} and t_{CYC} only in PCI-X mode. In conventional mode, the device must meet the requirements specified in PCI 2.2 for the appropriate clock frequency.

8. Device must meet this specification independent of how many outputs switch simultaneously.

9. The timing parameter t_{PCIVKH} is a minimum of 1.4 ns rather than the minimum of 1.2 ns in the PCI-X 1.0a Specification.

- 10. The timing parameter t_{PCRHFV} is a minimum of 10 clocks rather than the minimum of 5 clocks in the *PCI-X 1.0a Specification.*
- 11. Guaranteed by characterization.

12. Guaranteed by design.

High-Speed Serial Interfaces (HSSI)







Figure 42. Single-Ended Reference Clock Input DC Requirements

16.2.3 Interfacing with Other Differential Signaling Levels

- With on-chip termination to SGND_SRDSn (xcorevss), the differential reference clocks inputs are HCSL (high-speed current steering logic) compatible DC-coupled.
- Many other low voltage differential type outputs like LVDS (low voltage differential signaling) can be used but may need to be AC-coupled due to the limited common mode input range allowed (100 to 400 mV) for DC-coupled connection.
- LVPECL outputs can produce signal with too large amplitude and may need to be DC-biased at clock driver output first, then followed with series attenuation resistor to reduce the amplitude, in addition to AC-coupling.

NOTE

Figure 43 through Figure 46 below are for conceptual reference only. Due to the fact that clock driver chip's internal structure, output impedance, and termination requirements are different between various clock driver chip manufacturers, it is very possible that the clock circuit reference designs provided by clock driver chip vendor are different from what is shown below. They might also vary from one vendor to the other. Therefore, Freescale Semiconductor can neither provide the optimal clock driver reference circuits, nor guarantee the correctness of the following clock driver connection reference circuits. The system designer is recommended to contact the selected clock driver chip vendor for the optimal reference circuits with the SerDes reference clock receiver requirement provided in this document.

High-Speed Serial Interfaces (HSSI)

Figure 43 shows the SerDes reference clock connection reference circuits for HCSL type clock driver. It assumes that the DC levels of the clock driver chip is compatible with SerDes reference clock input's DC requirement.





Figure 44 shows the SerDes reference clock connection reference circuits for LVDS type clock driver. Since LVDS clock driver's common mode voltage is higher than the SerDes reference clock input's allowed range (100–400 mV), AC-coupled connection scheme must be used. It assumes the LVDS output driver features 50- Ω termination resistor. It also assumes that the LVDS transmitter establishes its own common mode level without relying on the receiver or other external component.



Figure 45 shows the SerDes reference clock connection reference circuits for LVPECL type clock driver. Since LVPECL driver's DC levels (both common mode voltages and output swing) are incompatible with the SerDes reference clock input's DC requirement, AC-coupling must be used. Figure 45 assumes that the LVPECL clock driver's output impedance is 50 Ω . R1 is used to DC-bias the LVPECL outputs prior

Package Description

Notes:

- 1. All dimensions are in millimeters.
- 2. Dimensioning and tolerancing per ASME Y14.5M-1994.
- 3. Maximum solder ball diameter measured parallel to datum A.
- 4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
- 5. Parallelism measurement shall exclude any effect of mark on top surface of package.
- 6. All dimensions are symmetric across the package center lines unless dimensioned otherwise.

Package Description



- 1. All dimensions are in millimeters.
- 2. Dimensioning and tolerancing per ASME Y14.5M-1994.
- 3. Maximum solder ball diameter measured parallel to datum A.
- 4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
- 5. Capacitors may not be present on all devices.
- 6. Caution must be taken not to short capacitors or exposed metal capacitor pads on package top.
- 7. Parallelism measurement shall exclude any effect of mark on top surface of package.
- 8. All dimensions are symmetric across the package center lines unless dimensioned otherwise.

Figure 56. Mechanical Dimensions and Bottom Surface Nomenclature of the FC-PBGA with Stamped Lid

Table 71. MPC8548E Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
MWE	E7	0	GV _{DD}	—
MCAS	H7	0	GV _{DD}	_
MRAS	L8	0	GV _{DD}	_
MCKE[0:3]	F10, C10, J11, H11	0	GV _{DD}	11
MCS[0:3]	K8, J8, G8, F8	0	GV _{DD}	_
MCK[0:5]	H9, B15, G2, M9, A14, F1	0	GV _{DD}	—
MCK[0:5]	J9, A15, G1, L9, B14, F2	0	GV _{DD}	—
MODT[0:3]	E6, K6, L7, M7	0	GV _{DD}	—
MDIC[0:1]	A19, B19	I/O	GV _{DD}	36
	Local Bus Controller Interface			•
LAD[0:31]	E27, B20, H19, F25, A20, C19, E28, J23, A25, K22, B28, D27, D19, J22, K20, D28, D25, B25, E22, F22, F21, C25, C22, B23, F20, A23, A22, E19, A21, D21, F19, B21	I/O	BV _{DD}	_
LDP[0:3]	K21, C28, B26, B22	I/O	BV _{DD}	—
LA[27]	H21	0	BV _{DD}	5, 9
LA[28:31]	H20, A27, D26, A28	0	BV _{DD}	5, 7, 9
LCS[0:4]	J25, C20, J24, G26, A26	0	ΒV _{DD}	
LCS5/DMA_DREQ2	D23	I/O	BV _{DD}	1
LCS6/DMA_DACK2	G20	0	BV _{DD}	1
LCS7/DMA_DDONE2	E21	0	BV _{DD}	1
LWE0/LBS0/LSDDQM[0]	G25	0	BV _{DD}	5, 9
LWE1/LBS1/LSDDQM[1]	C23	0	BV _{DD}	5, 9
LWE2/LBS2/LSDDQM[2]	J21	0	BV _{DD}	5, 9
LWE3/LBS3/LSDDQM[3]	A24	0	BV _{DD}	5, 9
LALE	H24	0	BV _{DD}	5, 8, 9
LBCTL	G27	0	BV _{DD}	5, 8, 9
LGPL0/LSDA10	F23	0	BV _{DD}	5, 9
LGPL1/LSDWE	G22	0	BV _{DD}	5, 9
LGPL2/LOE/LSDRAS	B27	0	BV _{DD}	5, 8, 9
LGPL3/LSDCAS	F24	0	BV _{DD}	5, 9
LGPL4/LGTA/LUPWAIT/LPBSE	H23	I/O	BV _{DD}	_
LGPL5	E26	0	BV _{DD}	5, 9
LCKE	E24	0	BV _{DD}	_
LCLK[0:2]	E23, D24, H22	0	BV _{DD}	—

Table 72.	MPC8547E	Pinout Listing	(continued)
		i mout Listing	(continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
	DFT			
L1_TSTCLK	AC25	I	OV _{DD}	25
L2_TSTCLK	AE22	I	OV _{DD}	25
LSSD_MODE	AH20	I	OV _{DD}	25
TEST_SEL	AH14	I	OV _{DD}	25
	Thermal Management			
THERMO	AG1			14
THERM1	AH1			14
	Power Management			
ASLEEP	AH18	0	OV_{DD}	9, 19, 29
	Power and Ground Signals			
GND	 A11, B7, B24, C1, C3, C5, C12, C15, C26, D8, D11, D16, D20, D22, E1, E5, E9, E12, E15, E17, F4, F26, G12, G15, G18, G21, G24, H2, H6, H8, H28, J4, J12, J15, J17, J27, K7, K9, K11, K27, L3, L5, L12, L16, N11, N13, N15, N17, N19, P4, P9, P12, P14, P16, P18, R11, R13, R15, R17, R19, T4, T12, T14, T16, T18, U8, U11, U13, U15, U17, U19, V4, V12, V18, W6, W19, Y4, Y9, Y11, Y19, AA6, AA14, AA17, AA22, AA23, AB4, AC2, AC11, AC19, AC26, AD5, AD9, AD22, AE3, AE14, AF6, AF10, AF13, AG8, AG27, K28, L24, L26, N24, N27, P25, R28, T24, T26, U24, V25, W28, Y24, Y26, AA24, AA27, AB25, AC28, L21, L23, N22, P20, R23, T21, U22, V20, W23, Y21, U27 	_	_	_
OV _{DD}	V16, W11, W14, Y18, AA13, AA21, AB11, AB17, AB24, AC4, AC9, AC21, AD6, AD13, AD17, AD19, AE10, AE8, AE24, AF4, AF12, AF22, AF27, AG26	Power for PCI and other standards (3.3 V)	OV _{DD}	
LV _{DD}	N8, R7, T9, U6	Power for TSEC1 and TSEC2 (2.5 V, 3.3 V)	LV _{DD}	—
TV _{DD}	W9, Y6	Power for TSEC3 and TSEC4 (2,5 V, 3.3 V)	TV _{DD}	_
GV _{DD}	B3, B11, C7, C9, C14, C17, D4, D6, D10, D15, E2, E8, E11, E18, F5, F12, F16, G3, G7, G9, G11, H5, H12, H15, H17, J10, K3, K12, K16, K18, L6, M4, M8, M13	Power for DDR1 and DDR2 DRAM I/O voltage (1.8 V, 2.5 V)	GV _{DD}	

Table 72. MPC8547E Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
SD_PLL_TPA	U26	0		24

Note: All note references in this table use the same numbers as those for Table 71. See Table 71 for the meanings of these notes.

Table 73 provides the pin-out listing for the MPC8545E 783 FC-PBGA package.

NOTE

All note references in the following table use the same numbers as those for Table 71. See Table 71 for the meanings of these notes.

Signal	Package Pin Number	Pin Type	Power Supply	Notes				
	PCI1 and PCI2 (One 64-Bit or Two 32-Bit)		1					
PCI1_AD[63:32]/PCI2_AD[31:0]	AB14, AC15, AA15, Y16, W16, AB16, AC16, AA16, AE17, AA18, W18, AC17, AD16, AE16, Y17, AC18, AB18, AA19, AB19, AB21, AA20, AC20, AB20, AB22, AC22, AD21, AB23, AF23, AD23, AE23, AC23, AC24	I/O	OV _{DD}	17				
PCI1_AD[31:0]	AH6, AE7, AF7, AG7, AH7, AF8, AH8, AE9, AH9, AC10, AB10, AD10, AG10, AA10, AH10, AA11, AB12, AE12, AG12, AH12, AB13, AA12, AC13, AE13, Y14, W13, AG13, V14, AH13, AC14, Y15, AB15	I/O	OV _{DD}	17				
PCI1_C_BE[7:4]/PCI2_C_BE[3:0]	AF15, AD14, AE15, AD15	I/O	OV _{DD}	17				
PCI1_C_BE[3:0]	AF9, AD11, Y12, Y13	I/O	OV _{DD}	17				
PCI1_PAR64/PCI2_PAR	W15	I/O	OV _{DD}	—				
PCI1_GNT[4:1]	AG6, AE6, AF5, AH5	0	OV _{DD}	5, 9, 35				
PCI1_GNT0	AG5	I/O	OV _{DD}	—				
PCI1_IRDY	AF11	I/O	OV _{DD}	2				
PCI1_PAR	AD12	I/O	OV _{DD}	—				
PCI1_PERR	AC12	I/O	OV _{DD}	2				
PCI1_SERR	V13	I/O	OV _{DD}	2, 4				
PCI1_STOP	W12	I/O	OV _{DD}	2				
PCI1_TRDY	AG11	I/O	OV _{DD}	2				
PCI1_REQ[4:1]	AH2, AG4, AG3, AH4	I	OV _{DD}	—				
PCI1_REQ0	AH3	I/O	OV _{DD}	—				
PCI1_CLK	AH26	I	OV _{DD}	39				
PCI1_DEVSEL	AH11	I/O	OV _{DD}	2				

Table 73. MPC8545E Pinout Listing

Package Description

Signal	Package Pin Number	Pin Type	Power Supply	Notes						
MDIC[0:1]	A19, B19	I/O	GV _{DD}	36						
Local Bus Controller Interface										
LAD[0:31]	E27, B20, H19, F25, A20, C19, E28, J23, A25, K22, B28, D27, D19, J22, K20, D28, D25, B25, E22, F22, F21, C25, C22, B23, F20, A23, A22, E19, A21, D21, F19, B21	I/O	BV _{DD}							
LDP[0:3]	K21, C28, B26, B22	I/O	BV _{DD}	_						
LA[27]	H21	0	BV _{DD}	5, 9						
LA[28:31]	H20, A27, D26, A28	0	BV _{DD}	5, 7, 9						
LCS[0:4]	J25, C20, J24, G26, A26	0	BV _{DD}	—						
LCS5/DMA_DREQ2	D23	I/O	BV _{DD}	1						
LCS6/DMA_DACK2	G20	0	BV _{DD}	1						
LCS7/DMA_DDONE2	E21	0	BV _{DD}	1						
LWE0/LBS0/LSDDQM[0]	G25	0	BV _{DD}	5, 9						
LWE1/LBS1/LSDDQM[1]	C23	0	BV _{DD}	5, 9						
LWE2/LBS2/LSDDQM[2]	J21	0	BV _{DD}	5, 9						
LWE3/LBS3/LSDDQM[3]	A24	0	BV _{DD}	5, 9						
LALE	H24	0	BV _{DD}	5, 8, 9						
LBCTL	G27	0	BV _{DD}	5, 8, 9						
LGPL0/LSDA10	F23	0	BV _{DD}	5, 9						
LGPL1/LSDWE	G22	0	BV _{DD}	5, 9						
LGPL2/LOE/LSDRAS	B27	0	BV _{DD}	5, 8, 9						
LGPL3/LSDCAS	F24	0	BV _{DD}	5, 9						
LGPL4/LGTA/LUPWAIT/LPBSE	H23	I/O	BV _{DD}	—						
LGPL5	E26	0	BV _{DD}	5, 9						
LCKE	E24	0	BV _{DD}	—						
LCLK[0:2]	E23, D24, H22	0	BV _{DD}	—						
LSYNC_IN	F27	I	BV _{DD}	—						
LSYNC_OUT	F28	0	BV _{DD}	—						
DMA										
DMA_DACK[0:1]	AD3, AE1	0	OV _{DD}	5, 9, 106						
DMA_DREQ[0:1]	AD4, AE2	I	OV _{DD}	-						
DMA_DDONE[0:1]	AD2, AD1	0	OV _{DD}	-						
	Programmable Interrupt Controller									

Signal	Package Pin Number	Pin Type	Power Supply	Notes					
	JTAG								
ТСК	AG28	I	OV _{DD}	_					
TDI	AH28	I	OV _{DD}	12					
TDO	AF28	0	OV _{DD}	—					
TMS	AH27	I	OV _{DD}	12					
TRST	AH23	I	OV _{DD}	12					
	DFT	I							
L1_TSTCLK	AC25	I	OV _{DD}	25					
L2_TSTCLK	AE22	I	OV _{DD}	25					
LSSD_MODE	AH20	I	OV _{DD}	25					
TEST_SEL	AH14	I	OV _{DD}	109					
Thermal Management									
THERM0	AG1		—	14					
THERM1	AH1		—	14					
Power Management									
ASLEEP	AH18	0	OV _{DD}	9, 19, 29					
	Power and Ground Signals								
GND	 A11, B7, B24, C1, C3, C5, C12, C15, C26, D8, D11, D16, D20, D22, E1, E5, E9, E12, E15, E17, F4, F26, G12, G15, G18, G21, G24, H2, H6, H8, H28, J4, J12, J15, J17, J27, K7, K9, K11, K27, L3, L5, L12, L16, N11, N13, N15, N17, N19, P4, P9, P12, P14, P16, P18, R11, R13, R15, R17, R19, T4, T12, T14, T16, T18, U8, U11, U13, U15, U17, U19, V4, V12, V18, W6, W19, Y4, Y9, Y11, Y19, AA6, AA14, AA17, AA22, AA23, AB4, AC2, AC11, AC19, AC26, AD5, AD9, AD22, AE3, AE14, AF6, AF10, AF13, AG8, AG27, K28, L24, L26, N24, N27, P25, R28, T24, T26, U24, V25, W28, Y24, Y26, AA24, AA27, AB25, AC28, L21, L23, N22, P20, R23, T21, U22, V20, W23, Y21, U27 	_							
OV _{DD}	V16, W11, W14, Y18, AA13, AA21, AB11, AB17, AB24, AC4, AC9, AC21, AD6, AD13, AD17, AD19, AE10, AE8, AE24, AF4, AF12, AF22, AF27, AG26	Power for PCI and other standards (3.3 V)	OV _{DD}	—					
LV _{DD}	N8, R7, T9, U6	Power for TSEC1 and TSEC2 (2.5 V, 3.3 V)	LV _{DD}	_					

Package Description

Signal	Package Pin Number	Pin Type	Power Supply	Notes
TV _{DD}	W9, Y6	Power for TSEC3 and TSEC4 (2,5 V, 3.3 V)	TV _{DD}	_
GV _{DD}	B3, B11, C7, C9, C14, C17, D4, D6, D10, D15, E2, E8, E11, E18, F5, F12, F16, G3, G7, G9, G11, H5, H12, H15, H17, J10, K3, K12, K16, K18, L6, M4, M8, M13	Power for DDR1 and DDR2 DRAM I/O voltage (1.8 V,2.5 V)	GV _{DD}	_
BV _{DD}	C21, C24, C27, E20, E25, G19, G23, H26, J20	Power for local bus (1.8 V, 2.5 V, 3.3 V)	BV _{DD}	—
V _{DD}	M19, N12, N14, N16, N18, P11, P13, P15, P17, P19, R12, R14, R16, R18, T11, T13, T15, T17, T19, U12, U14, U16, U18, V17, V19	Power for core (1.1 V)	V _{DD}	_
SV _{DD}	L25, L27, M24, N28, P24, P26, R24, R27, T25, V24, V26, W24, W27, Y25, AA28, AC27	Core power for SerDes transceivers (1.1 V)	SV _{DD}	_
XV _{DD}	L20, L22, N23, P21, R22, T20, U23, V21, W22, Y20	Pad power for SerDes transceivers (1.1 V)	XV _{DD}	_
AVDD_LBIU	J28	Power for local bus PLL (1.1 V)	_	26
AVDD_PCI1	AH21	Power for PCI1 PLL (1.1 V)	_	26
AVDD_PCI2	AH22	Power for PCI2 PLL (1.1 V)	Ι	26
AVDD_CORE	AH15	Power for e500 PLL (1.1 V)	_	26
AVDD_PLAT	AH19	Power for CCB PLL (1.1 V)	_	26
AVDD_SRDS	U25	Power for SRDSPLL (1.1 V)	—	26
SENSEVDD	M14	0	V _{DD}	13

Table 74. MPC8543E Pinout Listing (continued)

20 Clocking

This section describes the PLL configuration of the device. Note that the platform clock is identical to the core complex bus (CCB) clock.

20.1 Clock Ranges

Table 75 through Table 77 provide the clocking specifications for the processor cores and Table 78, through Table 80 provide the clocking specifications for the memory bus.

Characteristic	Maximum Processor Core Frequency			y MH-	Unit	Notos		
					1333 MITZ		Unit	notes
	Min	Мах	Min	Мах	Min	Мах		
e500 core processor frequency	800	1000	800	1200	800	1333	MHz	1, 2

 Table 75. Processor Core Clocking Specifications (MPC8548E and MPC8547E)

Notes:

 Caution: The CCB to SYSCLK ratio and e500 core to CCB ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB frequency do not exceed their respective maximum or minimum operating frequencies. See Section 20.2, "CCB/SYSCLK PLL Ratio," and Section 20.3, "e500 Core PLL Ratio," for ratio settings.

2.) The minimum e500 core frequency is based on the minimum platform frequency of 333 MHz.

Table 76. Processor Core Clocking Specifications (MPC8545E)

Characteristic	Maximum Processor Core Frequency							
	800 MHz		1000 MHz		1200 MHz		Unit	Notes
	Min	Max	Min	Max	Min	Max		
e500 core processor frequency	800	800	800	1000	800	1200	MHz	1, 2

Notes:

1. **Caution:** The CCB to SYSCLK ratio and e500 core to CCB ratio settings must be chosen such that the resulting SYSCLK frequency, e500 (core) frequency, and CCB frequency do not exceed their respective maximum or minimum operating frequencies. See Section 20.2, "CCB/SYSCLK PLL Ratio," and Section 20.3, "e500 Core PLL Ratio," for ratio settings.

2.)The minimum e500 core frequency is based on the minimum platform frequency of 333 MHz.

20.3 e500 Core PLL Ratio

This table describes the clock ratio between the e500 core complex bus (CCB) and the e500 core clock. This ratio is determined by the binary value of LBCTL, LALE, and LGPL2 at power up, as shown in this table.

Binary Value of LBCTL, LALE, LGPL2 Signals	e500 core:CCB Clock Ratio	Binary Value of LBCTL, LALE, LGPL2 Signals	e500 core:CCB Clock Ratio
000	4:1	100	2:1
001	9:2	101	5:2
010	Reserved	110	3:1
011	3:2	111	7:2

Table 82	. e500	Core t	o CCB	Clock Ratio
----------	--------	--------	-------	--------------------

20.4 Frequency Options

Table 83This table shows the expected frequency values for the platform frequency when using a CCB clock to SYSCLK ratio in comparison to the memory bus clock speed.

CCB to SYSCLK Ratio	SYSCLK (MHz)									
	16.66	25	33.33	41.66	66.66	83	100	111	133.33	
	Platform/CCB Frequency (MHz)									
2										
3								333	400	
4						333	400	445	533	
5					333	415	500			
6					400	500		-		
8				333	533					
9				375						
10			333	417						
12			400	500						
16		400	533		-					
20	333	500		-						

Table 83. Frequency Options of SYSCLK with Respect to Memory Bus Speeds

Note: Due to errata Gen 13 the max sys clk frequency must not exceed 100 MHz if the core clk frequency is below 1200 MHz.

Characteristic	JEDEC Board	Symbol	Value	Unit	Notes
Die junction-to-board	N/A	$R_{ extsf{ heta}JB}$	5	°C/W	3
Die junction-to-case	N/A	$R_{ ext{ heta}JC}$	0.8	°C/W	4

Table 85. Package Thermal Characteristics for FC-PBGA (continued)

Notes:

- 1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, airflow, power dissipation of other components on the board, and board thermal resistance.
- 2. Per JEDEC JESD51-6 with the board (JESD51-7) horizontal.
- 3. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- 4. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1). The cold plate temperature is used for the case temperature, measured value includes the thermal resistance of the interface layer.

21.3 Heat Sink Solution

Every system application has different conditions that the thermal management solution must solve. As such, providing a recommended heat sink has not been found to be very useful. When a heat sink is chosen, give special consideration to the mounting technique. Mounting the heat sink to the printed-circuit board is the recommended procedure using a maximum of 10 lbs force (45 Newtons) perpendicular to the package and board. Clipping the heat sink to the package is not recommended.

22 System Design Information

This section provides electrical design recommendations for successful application of the device.

22.1 System Clocking

This device includes five PLLs, as follows:

- 1. The platform PLL generates the platform clock from the externally supplied SYSCLK input. The frequency ratio between the platform and SYSCLK is selected using the platform PLL ratio configuration bits as described in Section 20.2, "CCB/SYSCLK PLL Ratio."
- 2. The e500 core PLL generates the core clock as a slave to the platform clock. The frequency ratio between the e500 core clock and the platform clock is selected using the e500 PLL ratio configuration bits as described in Section 20.3, "e500 Core PLL Ratio."
- 3. The PCI PLL generates the clocking for the PCI bus.
- 4. The local bus PLL generates the clock for the local bus.
- 5. There is a PLL for the SerDes block.

22.2 PLL Power Supply Filtering

Each of the PLLs listed above is provided with power through independent power supply pins (AV_{DD}_PLAT, AV_{DD}_CORE, AV_{DD}_PCI, AV_{DD}_LBIU, and AV_{DD}_SRDS, respectively). The AV_{DD}

• SD_REF_CLK

NOTE

It is recommended to power down the unused lane through SRDSCR1[0:7] register (offset = $0xE_0F08$) (this prevents the oscillations and holds the receiver output in a fixed state) that maps to SERDES lane 0 to lane 7 accordingly.

Pins V28 and M26 must be tied to XV_{DD} . Pins V27 and M25 must be tied to GND through a 300- Ω resistor.

22.11 Guideline for PCI Interface Termination

PCI termination if PCI 1 or PCI 2 is not used at all.

Option 1

If PCI arbiter is enabled during POR:

- All AD pins are driven to the stable states after POR. Therefore, all ADs pins can be floating.
- All PCI control pins can be grouped together and tied to OV_{DD} through a single 10-k Ω resistor.
- It is optional to disable PCI block through DEVDISR register after POR reset.

Option 2

If PCI arbiter is disabled during POR:

- All AD pins are in the input state. Therefore, all ADs pins need to be grouped together and tied to OV_{DD} through a single (or multiple) 10-k Ω resistor(s).
- All PCI control pins can be grouped together and tied to OV_{DD} through a single 10-k Ω resistor.
- It is optional to disable PCI block through DEVDISR register after POR reset.

22.12 Guideline for LBIU Termination

If the LBIU parity pins are not used, the following is the termination recommendation:

- For LDP[0:3]—tie them to ground or the power supply rail via a 4.7-k Ω resistor.
- For LPBSE—tie it to the power supply rail via a 4.7-k Ω resistor (pull-up resistor).